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View Online at https://aerobasegroup.com/nsn/5962-01-359-3247 **Body Length:** 1.485 inches **Body Width:** Between 0.240 inches and 0.310 inches **Body Height:** Between 0.115 inches and 0.195 inches **Maximum Power Dissipation Rating:** 1500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and programmable and ultraviolet erasable and bidirectional and w/clock and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 24 input **Current Rating Per Characteristic:** 300.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -2.0 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 10.00 input picofarads and 12.00 output picofarads **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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